

isc Silicon NPN Power Transistor

2SD1110

DESCRIPTION

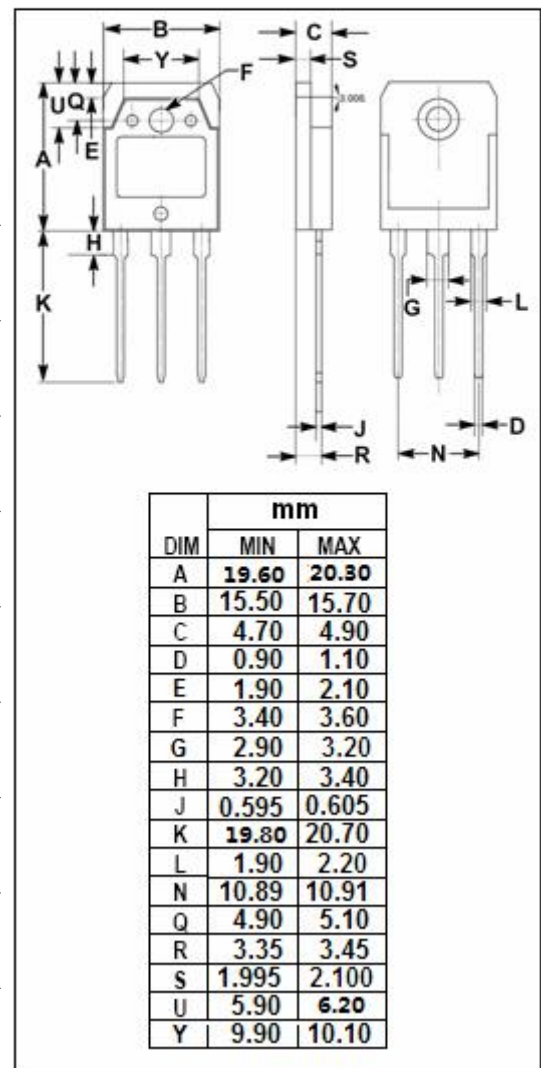
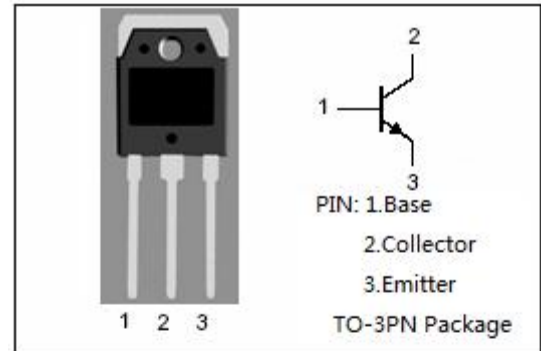
- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 120V(\text{Min})$
- Good Linearity of h_{FE}
- Complement to Type 2SB849
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for audio frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	120	V
V_{CEO}	Collector-Emitter Voltage	120	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	7	A
I_{CP}	Collector Current-Pulse	12	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	80	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



isc Silicon NPN Power Transistor**2SD1110****ELECTRICAL CHARACTERISTICS****T_C=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5.0A; I _B = 0.5A			2.0	V
V _{BE(sat)}	Base -Emitter Saturation Voltage	I _C = 5.0A; I _B = 0.5A			2.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 120V; I _E = 0			50	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 3V; I _C = 0			50	μ A
h _{FE-1}	DC Current Gain	I _C = 50mA; V _{CE} = 5V	20			
h _{FE-2}	DC Current Gain	I _C = 1A; V _{CE} = 5V	40	80	200	
C _{OB}	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		190		pF
f _T	Current-Gain—Bandwidth Product	I _C = 0.2A; V _{CE} = 5V		15		MHz

◆ h_{FE-2} Classifications

S	R	Q
40-80	60-120	100-200

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